

# Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

## **Quality Overview**

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
  - Class Q Military
  - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
- Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

# Advanced Micro Devices

# PAL16R8 Family

# 20-Pin TTL Programmable Array Logic

#### **DISTINCTIVE CHARACTERISTICS**

- As fast as 4.5 ns maximum propagation delay
- Popular 20-pin architectures: 16L8, 16R8, 16R6, 16R4
- Programmable replacement for high-speed TTL logic
- Register preload for testability
- Power-up reset for initialization

- Extensive third-party software and programmer support through FusionPLD partners
- 20-pin DIP and PLCC packages save space
- 28-pin PLCC-4 package provides ultra-clean high-speed signals

#### **GENERAL DESCRIPTION**

The PAL16R8 Family (PAL16L8, PAL16R8, PAL16R6, PAL16R4) includes the PAL16R8-5/4 Series which provides the highest speed in the 20-pin TTL PAL device family, making the series ideal for high-performance applications. The PAL16R8 Family is provided with standard 20-pin DIP and PLCC pinouts and a 28-pin PLCC pinout. The 28-pin PLCC pinout contains seven extra ground pins interleaved between the outputs to reduce noise and increase speed.

The family utilizes Advanced Micro Devices' advanced trench-isolated bipolar process and fuse-link technology. The devices provide user-programmable logic for replacing conventional SSI/MSI gates and flip-flops at a reduced chip count.

The family allows the systems engineer to implement the design on-chip, by opening fuse links to configure AND and OR gates within the device, according to the desired logic function. Complex interconnections between gates, which previously required time-consuming layout, are lifted from the PC board and placed on silicon, where they can be easily modified during prototyping or production.

The PAL device implements the familiar Boolean logic transfer function, the sum of products. The PAL device

is a programmable AND array driving a fixed OR array. The AND array is programmed to create custom product terms, while the OR array sums selected terms at the outputs.

In addition, the PAL device provides the following options:

- Variable input/output pin ratio
- Programmable three-state outputs
- Registers with feedback

Product terms with all connections opened assume the logical HIGH state; product terms connected to both true and complement of any single input assume the logical LOW state. Registers consist of D-type flip-flops that are loaded on the LOW-to-HIGH transition of the clock. Unused input pins should be tied to Vcc or GND.

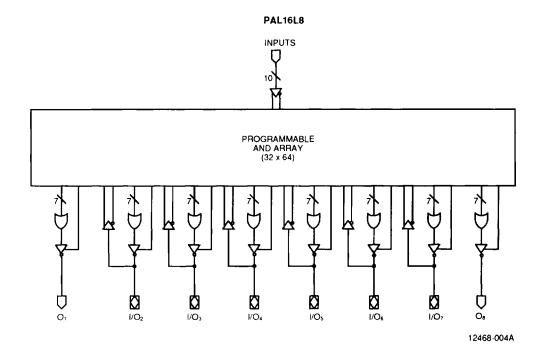
The entire PAL device family is supported by the FusionPLD partners. The PAL family is programmed on conventional PAL device programmers with appropriate personality and socket adapter modules. Once the PAL device is programmed and verified, an additional connection may be opened to prevent pattern readout. This feature secures proprietary circuits.

#### PRODUCT SELECTOR GUIDE

DEVICE	DEDICATED INPUTS	OUTPUTS	PRODUCT TERMS/ OUTPUT	FEEDBACK	ENABLE
PAL16L8	10	6 comb. 2 comb.	7 7	I/O -	prog. prog.
PAL16R8	8	8 reg.	8	reg.	pin
PAL16R6	8	6 reg. 2 comb.	8 7	reg. I/O	pin prog.
PAL16R4	8	4 reg. 4 comb.	8 7	reg. I/O	pin prog.

Publication#	16492	Rev. A	Amendment/0
issue Date:	January	1992	

# **BLOCK DIAGRAMS**



# PROGRAMMABLE AND ARRAY (32 x 64)

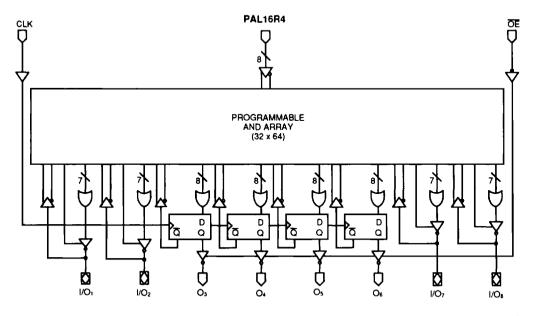
PAL16R8

12468-001A

#### **BLOCK DIAGRAMS**

# PAL16R6 CLK INPUTS PROGRAMMABLE AND ARRAY (32 x 64) THE COLOR TO THE COLOR TO

12468-002A



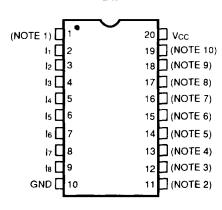
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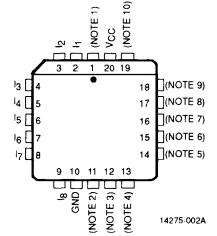
# **CONNECTION DIAGRAMS**

#### **Top View**



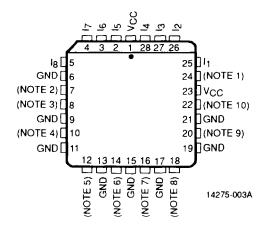
#### 20-Pin PLCC





14275-001A

#### 28-Pin PLCC



#### PIN DESIGNATIONS

CLK	Clock
GND	Ground
1	Input
I/O	Input/Output
0	Output
ŌĒ	Output Enable
Vcc	Supply Voltage

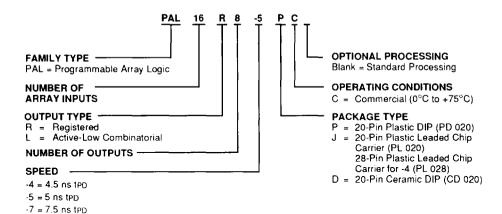
#### Note:

Pin 1 is marked for orientation.

Note	16L8	16R8	16R6	16R4
1	lo	CLK	CLK	CLK
2	t <sub>9</sub>	ŌĒ	E	ŌĒ
3	O <sub>1</sub>	O <sub>1</sub>	I/O <sub>1</sub>	I/O <sub>1</sub>
4	I/O <sub>2</sub>	O <sub>2</sub>	O <sub>2</sub>	I/O <sub>2</sub>
5	I/O <sub>3</sub>	Оз	O3	Оз
6	1/04	O <sub>4</sub>	O <sub>4</sub>	O <sub>4</sub>
7	1/O <sub>5</sub>	O <sub>5</sub>	O <sub>5</sub>	O <sub>5</sub>
8	1/06	O <sub>6</sub>	O <sub>6</sub>	O <sub>6</sub>
9	1/07	O7	<b>O</b> 7	1/07
10	Ов	O <sub>8</sub>	1/08	I/O <sub>8</sub>

# ORDERING INFORMATION Commercial Products

AMD programmable logic products for commercial applications are available with several ordering options. The order number (Valid Combination) is formed by a combination of:



Valid Combinations				
Yana	Combinations			
PAL16L8				
PAL16R8	–5PC. –5JC. –4JC			
PAL16R6	-560, -500, -400			
PAL16R4				
PAL16L8-7				
PAL16R8-7	PC. JC. DC			
PAL16R6-7	, 5, 55, 55			
PAL16R4-7				

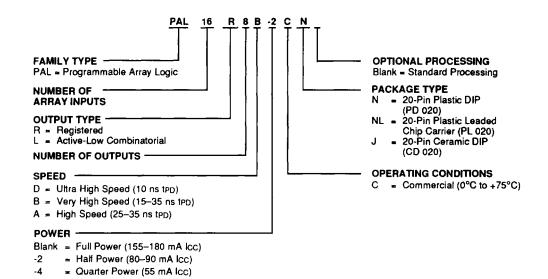
#### **Valid Combinations**

The Valid Combinations table lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, and to check on newly released combinations.

Note: Marked with AMD logo.

# ORDERING INFORMATION Commercial Products (MMI Marking Only)

AMD programmable logic products for commercial applications are available with several ordering options. The order number (Valid Combination) is formed by a combination of:



Valid Combinations						
PAL16L8	D, B,	CN, CNL, CJ				
PAL16R8	B-2, A,					
PAL16R6	B-4					
PAL16R4						

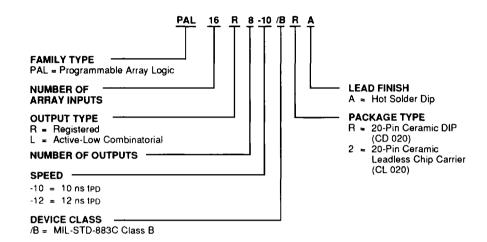
#### **Valid Combinations**

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Note: Marked with MMI logo.

# ORDERING INFORMATION APL Products

AMD programmable logic products for Aerospace and Defense applications are available with several ordering options. APL (Approved Products List) products are fully compliant with MIL-STD-883 requirements. The order number (Valid Combination) is formed by a combination of:



Valid Combinations					
PAL16L8					
PAL16R8	10 10	(DDA /DOA			
PAL16R6	-10, -12	/BRA, /B2A			
PAL16R4					

#### **Valid Combinations**

The Valid Combinations table lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.

Note: Marked with AMD logo.

#### **Group A Tests**

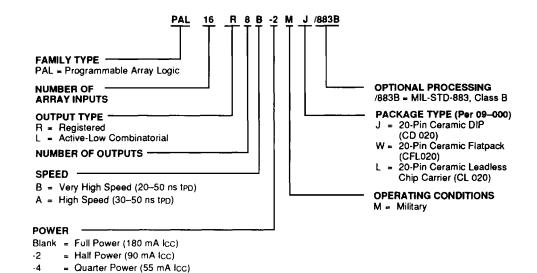
Group A Tests consist of Subgroups: 1, 2, 3, 7, 8, 9, 10, 11.

#### Military Burn-In

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Methods 1015, Conditions A through E. Test conditions are selected at AMD's option.

# ORDERING INFORMATION APL Products (MMI Marking Only)

AMD programmable logic products for Aerospace and Defense applications are available with several ordering options. APL (Approved Products List) products are fully compliant with MIL-STD-883 requirements. The order number (Valid Combination) is formed by a combination of:



Valid Combinations						
PAL16L8	B, B-2,	MJ/883B,				
PAL16R8	A, B-4	MW/883B,				
PAL16R6		ML/883B				
PAL16R4						

#### Valid Combinations

The Valid Combinations table lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional information on AMD's Standard Military grade products.

Note: Marked with MMI logo.

#### Group A Tests

Group A Tests consist of Subgroups: 1, 2, 3, 7, 8, 9, 10, 11.

#### Military Burn-In

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Methods 1015, Conditions A through E. Test conditions are selected at AMD's option.

# FUNCTIONAL DESCRIPTION Standard 20-pin PAL Family

The standard bipolar 20-pin PAL family devices have common electrical characteristics and programming procedures. Four different devices are available, including both registered and combinatorial devices. All parts are produced with a fuse link at each input to the AND gate array, and connections may be selectively removed by applying appropriate voltages to the circuit. Utilizing an easily-implemented programming algorithm, these products can be rapidly programmed to any customized pattern. Extra test words are preprogrammed during manufacturing to ensure extremely high field programming yields, and provide extra test paths to achieve excellent parametric correlation.

#### **Pinouts**

The PAL16R8 Family is available in the standard 20-pin DIP and PLCC pinouts and the PAL16R8-4 Series is available in the new 28-pin PLCC pinout. The 28-pin PLCC pinout gives the designer the cleanest possible signal with only 4.5 ns delay.

The PAL16R8-4 pinout has been designed to minimize the noise that can be generated by high-speed signals. Because of its inherently shorter leads, the PLCC package is the best package for use in high-speed designs. The short leads and multiple ground signals reduce the effective lead inductance, minimizing ground bounce. Placing the ground pins between the outputs optimizes the ground bounce protection, and also isolates the outputs from each other, eliminating cross-talk. This pinout can reduce the effective propagation delay by as much as 20% from a standard DIP pinout. Design files for PAL16R8-4 Series devices are written as if the device had a standard 20-pin DIP pinout for most design software packages.

#### Variable Input/Output Pin Ratio

The registered devices have eight dedicated input lines, and each combinatorial output is an I/O pin. The PAL16L8 has ten dedicated input lines and six of the eight combinatorial outputs are I/O pins. Buffers for device inputs have complementary outputs to provide user-programmable input signal polarity. Unused input pins should be tied to Vcc or GND.

#### **Programmable Three-State Outputs**

Each output has a three-state output buffer with three-state control. On combinatorial outputs, a product term controls the buffer, allowing enable and disable to be a function of any product of device inputs or output feedback. The combinatorial output provides a bidirectional I/O pin and may be configured as a dedicated input if the output buffer is always disabled. On registered outputs, an input pin controls the enabling of the three-state outputs.

#### Registers with Feedback

Registered outputs are provided for data storage and synchronization. Registers are composed of D-type flip-flops that are loaded on the LOW-to-HIGH transition of the clock input.

#### Register Preload

The register on the PAL16R8 Family can be preloaded from the output pins to facilitate functional testing of complex state machine designs. This feature allows direct loading of arbitrary states, making it unnecessary to cycle through long test vector sequences to reach a desired state. In addition, transitions from illegal states can be verified by loading illegal states and observing proper recovery.

## **Power-Up Reset**

All flip-flops power-up to a logic LOW for predictable system initialization. Outputs of the PAL16R8 Family will be HIGH due to the active-low outputs. The Vcc rise must be monotonic and the reset delay time is 1000 ns maximum.

#### **Security Fuse**

After programming and verification, a PAL16R8 Family design can be secured by programming the security fuse. Once programmed, this fuse defeats readback of the internal programmed pattern by a device programmer, securing proprietary designs from competitors. When the security fuse is programmed, the array will read as if every fuse is programmed.

#### **Quality and Testability**

The PAL16R8 Family offers a very high level of built-in quality. Extra programmable fuses provide a means of verifying performance of all AC and DC parameters. In addition, this verifies complete programmability and functionality of the device to provide the highest programming yields and post-programming functional yields in the industry.

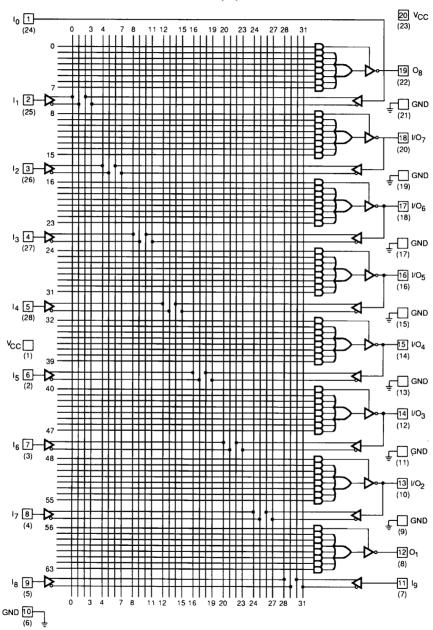
#### **Technology**

The PAL16R8 Family is fabricated with AMD's advanced trench-isolated bipolar process. This process reduces parasitic capacitances and minimum geometries to provide higher performance. The array connections are formed with proven TiW fuses for reliable operation.

#### **LOGIC DIAGRAM**

## DIP and 20-Pin PLCC (28-Pin PLCC) Pinouts

16L8 (-4)

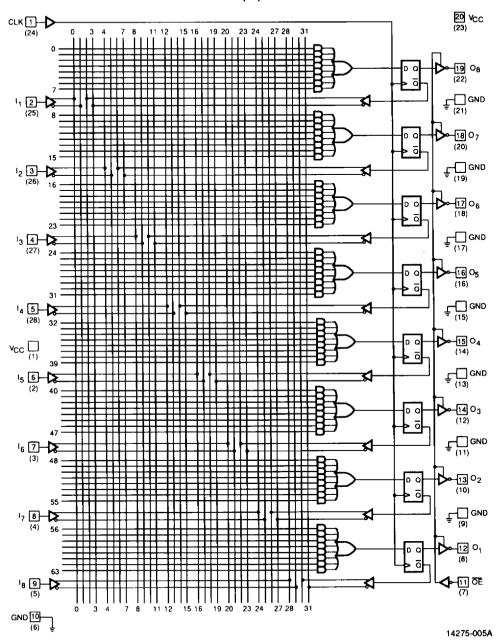


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# LOGIC DIAGRAM

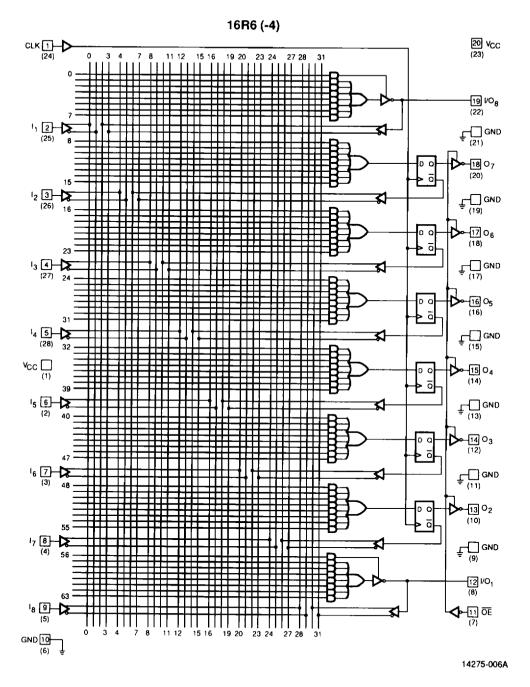
# DIP and 20-Pin PLCC (28-Pin PLCC) Pinouts

16R8 (-4)

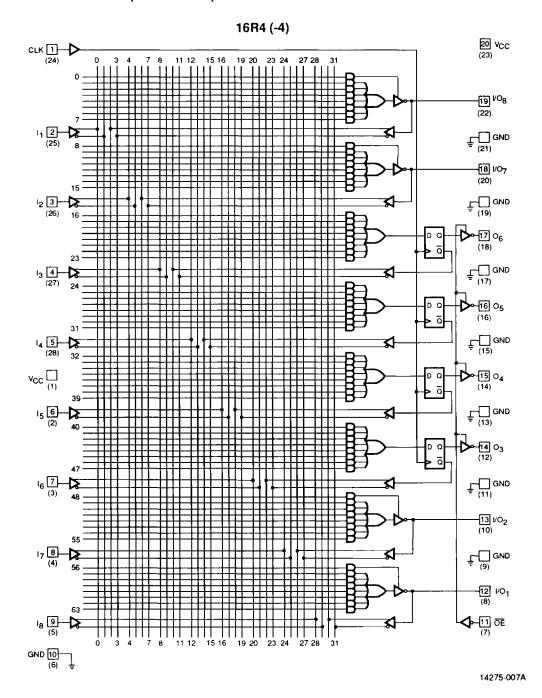


#### LOGIC DIAGRAM

# DIP and 20-Pin PLCC (28-Pin PLCC) Pinouts



# LOGIC DIAGRAM DIP and 20-Pin PLCC (28-Pin PLCC) Pinouts





Ambient Temperature with

Power Applied -65°C to +150°C

Storage Temperature

-55°C to +125°C

Supply Voltage with

-0.5 V to +7.0 V Respect to Ground

DC Input Voltage

-1.2 V to Vcc + 0.5 V

DC Input Current

-30 mA to +5 mA

DC Output or I/O Pin Voltage -0.5 V to Vcc + 0.5 V

Static Discharge Voltage

2001 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

#### **OPERATING RANGES**

Ambient Temperature (TA)

Operating in Free Air

0°C to +75°C

Supply Voltage (Vcc)

with Respect to Ground

+4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

#### DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	IOH = -3.2 mA VIN = VIH OF VIL VCC = Min.	2.4		٧
Vol	Output LOW Voltage	IOL = 24 mA VIN = VIH OF VIL VCC = MIN.		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		8.0	٧
Vi	Input Clamp Voltage	In = -18 mA, Vcc = Min.		-1.2	٧
lıн	Input HIGH Current	V <sub>IN</sub> = 2.7 V, V <sub>CC</sub> = Max. (Note 2)		25	μА
l <sub>IL</sub>	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max. (Note 2)		-250	μА
lı .	Maximum Input Current	VIN = 5.5 V, VCC = Max.		1_	mA
Іогн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max. Vin = Vih or Vil (Note 2)		100	μА
lozı	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vih or Vil (Note 2)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max. (Note 3)	-30	-130	mA
Icc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (lout = 0 mA) Vcc = Max.		210	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Descrip	otion	Test Conditions		Тур.	Unit
Cin	Input Capacitance	CLK, OE	Vin = 2.0 V	Vcc = 5.0 V	8	
		l1- <b>l</b> 8		T <sub>A</sub> = 25°C	5	pF
Соит	Output Capacitance	)	Vout = 2.0 V	f = 1 MHz	8	

#### Note:

## **SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)**

					-5		-4		
Parameter Symbol	Parameter Description				Min. (Note 3)	Max.	Min. (Note 3)	Max.	Unit
tpp	Input or Fee Combinatori			16L8, 16R8, 16R4	1	5	1	4.5	ns
ts	Setup Time t Feedback to	from Input or Clock			4.5		4.5		ns
tн	Hold Time				0		0		ns
tco	Clock to Out	put	out		1	4.0	1	3.5	ns
tskewr	Skew Betwe Outputs (Not	en Registered e 4)		16R8, 16R6,		1		0.5	ns
twL		LOW	LOW		4		4		ns
twн	Clock Width	HIGH		16R4	4		4		ns
	Maximum	External Feedback	1/(ts + tco)	1	117		125		MHz
fmax	Frequency	Internal Feedback		1	125_		125		MHz
	(Note 5)	No Feedback	1/(tw+ + twL)		125		125		MHz
tezx	OE to Outpu	t Enable		]	1	6.5	1_	6.5	ns
tpxz	OE to Outpu	to Output Disable			1	5	1	5	ns
tea	Input to Outp Product Terr	tput Enable Using rm Control		16L8, 16R6,	2	6.5	2	6.5	ns
ter	Input to Outp Product Terr	out Disable Using in Control		16R4	2	5	2	5	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Delay minimums for tpp, tco, tpzx, tpxz, tex, and ten are chosen based on two considerations: they must allow for the large number of variables that define "best case" conditions, and they must attempt to anticipate possible future process enhancements that may increase performance. It is possible that such process improvements may someday push the minimum delays beyond what was originally anticipated; therefore minimums should be used with care, and are recommended primarily for simulation.
- 4. Skew testing takes into account pattern and switching direction differences between outputs.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where the frequency may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature -65°C to +150°C

Ambient Temperature with

Power Applied

-55°C to +125°C

Supply Voltage with

-0.5 V to +7.0 V Respect to Ground

-1.2 V to +7.0 V DC Input Voltage

DC Input Current -30 mA to +5 mA

DC Output or I/O Pin Voltage -0.5 V to Vcc + 0.5 VStatic Discharge Voltage 2001 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

#### **OPERATING RANGES**

#### Commercial (C) Devices

Ambient Temperature (TA)

Operating in Free Air

Supply Voltage (Vcc)

with Respect to Ground

+4.75 V to +5.25 V

0°C to +75°C

Operating ranges define those limits between which the functionality of the device is guaranteed.

#### DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	IOH = -3.2 mA VIN = VIH or VIL VCC = Min.	2.4		٧
Vol	Output LOW Voltage	IoL = 24 mA VIN = VIH or VIL Vcc = Min.		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		<b>V</b>
ViL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	V
Vı	Input Clamp Voltage	I <sub>IN</sub> = -18 mA, V <sub>CC</sub> = Min.		-1.2	٧
lн	Input HIGH Current	V <sub>IN</sub> = 2.7 V, V <sub>CC</sub> = Max. (Note 2)		25	μА
lıı.	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max. (Note 2)		-250	μА
<u>lı</u>	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max.		1	mA
Іохн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max. Vin = Vin or Vil (Note 2)		100	μА
lozL	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vih or Vil (Note 2)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max. (Note 3)	-30	-130	mΑ
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (lout = 0 mA) V <sub>CC</sub> = Max.		180	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and lozt (or IIH and lozH).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Description	Test Conditions		Тур.	Unit
Cin	Input Capacitance	VIN = 2.0 V	Vcc = 5.0 V T <sub>A</sub> = 25°C	5	pF
Соит	Output Capacitance	Vout = 2.0 V	f = 1 MHz	8	рг

#### Note:

## **SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)**

Parameter Symbol	Parameter Des	Parameter Description					Unit
	Input or Feedba	ack to		16L8, 16R6,	3	7.5	
tpD	PD Combinatorial Output		1 Output Switching	16R4	3	7	ns :
ts	Setup Time from Input or Feedback to Clock			7		ns	
tн	Hold Time				0		ns
tco	Clock to Output				3	6.5	ns
tskew	Skew Between	ew Between Registered Outputs (Note 4)				1	ns
twL	Clock Width	LOW	LOW		5		ns
twн	CIOCK WIGHT	HIGH			5		ns
	Maximum	External Feedb	ack 1/(ts + tco)	]	74		MHz
fmax	Frequency	Internal Feedba	Pack (fcnt)		100		MHz
	(Note 5)	No Feedback	1/(tw+ + twL)		100		MHz
tpzx	OE to Output E	nable			3	8	ns
texz	OE to Output Disable			3	8	ns	
tea	Input to Output Enable Using Product Term Control		16L8, 16R6,	3	10	ns	
ten	Input to Output	Disable Using Pro	oduct Term Control	16R4	3	10	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Output delay minimums are measured under best-case conditions.
- 4. Skew is measured with all outputs switching in the same direction.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where the frequency may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



-65°C to +150°C

-55°C to +125°C

-0.5 V to +7.0 V

-1.5 V to +5.5 V

-0.5 V to +5.5 V

Ambient Temperature with

Storage Temperature

Power Applied

Supply Voltage with

Respect to Ground

DC Input Voltage DC Output or I/O Pin Voltage

Static Discharge Voltage

OPERATING RANGES Commercial (C) Devices

Ambient Temperature (TA)

Operating in Free Air

Supply Voltage (Vcc)

with Respect to Ground

+4.75 V to +5.25 V

0°C to +75°C

Operating ranges define those limits between which the func-

tionality of the device is guaranteed.

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

#### DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

2001 V

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	IOH = -3.2 mA VIN = VIH OF VIL VCC = Min.	2.4		٧
Vol	Output LOW Voltage	IOL = 24 mA VIN = VIH OR VIL VCC = Min.		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		V
ViL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vı	Input Clamp Voltage	I <sub>IN</sub> = -18 mA, V <sub>CC</sub> = Min.		-1.5	٧
liн	Input HIGH Current	V <sub>IN</sub> = 2.4 V, V <sub>CC</sub> = Max. (Note 2)		25	μА
l <sub>IL</sub>	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max. (Note 2)		-250	μА
lı	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max.		100	μА
Іохн	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max. Vin = Vih or Vil (Note 2)		100	μА
lozi	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. V <sub>IN</sub> = V <sub>I</sub> H or V <sub>I</sub> L (Note 2)		-100	μA
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max. (Note 3)	-30	-130	mΑ
Icc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (lout = 0 mA) V <sub>CC</sub> = Max.		180	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of lit and lozt (or lin and lozh).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second, Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Description	Test Conditio	ns		Тур.	Unit
Cin	Input Capacitance	VIN = 2.0 V	Vcc = 5.0 V	CLK, OE	9	
			Ta = 25°C	Other Inputs	2	ρF
Соит	Output Capacitance	V <sub>OUT</sub> = 2.0 V	f≈1 MHz	Outputs	4	

#### Note:

# **SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)**

Parameter Symbol	Parameter Desc	cription			Min. (Note 3)	Max.	Unit
tpp	Input or Feedbac Combinatorial O			16L8, 16R6, 16R4	3	10	ns
ts	Setup Time from	Input or Feedback to	Clock		10		ns
tH	Hold Time				0		ns
tco	Clock to Output				2	7	ns
twL	Clock Width	LOW	LOW		8		ns
twн		HIGH		16R8, 16R6,	8		ns
	Maximum	External Feedback	1/(ts + tco)	16R4	58.8		MHz
fmax	Frequency	Internal Feedback (fcnt)			60		MHz
	(Note 5)	No Feedback	1/(tw+ + twL)		62.5		MHz
tezx	OE to Output En	able			3	10	ns
texz	OE to Output Disable				3	10	ns
tea	Input to Output Enable Using Product Term Control			16L8, 16R6,	1	10	ns
ten	Input to Output [	Disable Using Product	Term Control	16R4	1	10	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Output delay minimums are measured under best-case conditions.
- 4. Calculated from measured fMAX internal.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where the frequency may be affected.

<sup>1.</sup> These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



-65°C to +150°C Storage Temperature

Ambient Temperature with

Power Applied

-55°C to +125°C

Supply Voltage with

Respect to Ground -0.5 V to +7.0 V

 $-1.5 \text{ V to V}_{CC} + 0.5 \text{ V}$ DC Input Voltage

DC Output or I/O Pin Voltage -0.5 V to  $V_{CC} + 0.5 \text{ V}$ 

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

#### **OPERATING RANGES**

Commercial (C) Devices

Ambient Temperature (TA)

Operating in Free Air

0°C to +75°C

Supply Voltage (Vcc)

with Respect to Ground

+4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

#### DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	IOH = -3.2 mA VIN = VIH OF VIL VCC = MIN.	2.4		٧
Vol	Output LOW Voltage	IOL = 24 mA VIN = VIH Or VIL VCC = Min.		0.5	٧
Vıн	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		>
ViL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	>
Vı	Input Clamp Voltage	lın = −18 mA, Vcc = Min.		-1.2	٧
liн —	Input HIGH Current	V <sub>IN</sub> = 2.4 V, V <sub>CC</sub> = Max. (Note 2)	,	25	μА
HL	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max. (Note 2)		-250	μА
ħ	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max.		100	μА
ЮZН	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max. V <sub>IN</sub> = V <sub>I</sub> H or V <sub>I</sub> L (Note 2)		100	μА
lozu	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vih or Vil (Note 2)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max. (Note 3)	-30	-130	mA
lcc	Supply Current	Vin = 0 V, Outputs Open (lout = 0 mA) Vcc = Max.		180	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Description	Test Conditions		Тур.	Unit
Cin	Input Capacitance	VIN = 2.0 V	Vcc = 5.0 V T <sub>A</sub> = 25°C	8	
Соит	Output Capacitance	Vout = 2.0 V	f = 1 MHz	9	pF

#### Note:

#### **SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)**

						-	
Parameter Symbol	Parameter Desc	Parameter Description				Max.	Unit
tPD	Input or Feedback to Combinatorial Output		16L8, 16R6, 16R4		15	ns	
ts	Setup Time from Input or Feedback to Clock			15		ns	
th	Hold Time				0		ns
tco	Clock to Output	or Feedback				12	ns
twL	Clock Width	LOW		16R8, 16R6,	10		ns
twн		HIGH		16R4	10		ns
4	Maximum	External Feedback	1/(ts + tco)		37		MHz
f MAX	Frequency (Note 3)	No Feedback	1/(tw+ + twL)		50		MHz
tpzx	OE to Output En	able				15	ns
texz	OE to Output Disable			_		15	ns
1EA	Input to Output Enable Using Product Term Control			16L8, 16R6,		15	ns
tea	Input to Output D	Disable Using Product	Term Control	16R4		15	ns

- 2. See Switching Test Circuit for test conditions.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature -65°C to +150°C

Ambient Temperature with

**Power Applied** -55°C to +125°C

Supply Voltage with

-0.5 V to +7.0 V Respect to Ground

DC Input Voltage -1.5 V to Vcc + 0.5 V

-0.5 V to Vcc + 0.5 V DC Output or I/O Pin Voltage

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

#### **OPERATING RANGES**

Commercial (C) Devices

Ambient Temperature (T<sub>A</sub>)

Operating in Free Air

0°C to +75°C

Supply Voltage (Vcc)

with Respect to Ground

+4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

#### DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	IOH = -3.2 mA VIN = VIH OF VIL VCC = Min.	2.4		٧
Vol	Output LOW Voltage	IoL = 24 mA VIN = VIH or VIL Vcc = Min.		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		8.0	٧
Vı	Input Clamp Voltage	I <sub>IN</sub> = -18 mA, V <sub>CC</sub> = Min.		-1.2	٧
lін	Input HIGH Current	V <sub>IN</sub> = 2.7 V, V <sub>CC</sub> = Max. (Note 2)		25	μА
lıL	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max. (Note 2)		-100	μА
ħ	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max.		100	μА
lozн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max. V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> (Note 2)		100	μА
lozL	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vih or Vil (Note 2)		-100	μΑ
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max. (Note 3)	-30	-130	mA
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (lout = 0 mA) V <sub>CC</sub> = Max.		90	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and lozL (or IIH and lozH).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Description	Test Conditions		Тур.	Unit
Cin	Input Capacitance	VIN = 2.0 V	Vcc = 5.0 V	7	1
Соит	Output Capacitance	Vout = 2.0 V	Ta = 25°C f = 1 MHz	7	pF

#### Note:

 These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

# **SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)**

Parameter Symbol	Parameter Des	Parameter Description					Unit
tpD	Input or Feedback to Combinatorial Output		16L8, 16R6, 16R4		25	ns	
ts	Setup Time from	n Input or Feedback to	Clock		25		ns
tн	Hold Time				0		ns
tco	Clock to Output					15	ns
twL	Clock Width	LOW	LOW		15		ns
twн		HIGH		16R4	15		ns
	Maximum	External Feedback	1/(ts + tco)		25		MHz
fMAX	Frequency	Internal Feedback (	CNT)		28.5		MHz
	(Note 4)	No Feedback	1/(tw+ + twL)		33		MHz
tezx	OE to Output E	nable				20	ns
texz	OE to Output Disable					20	ns
tea	Input to Output Enable Using Product Term Control			16L8, 16R6,		25	ns
ter	Input to Output	Disable Using Product	Term Control	16R4		25	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Calculated from measured fMAx internal.
- 4. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.



Storage Temperature -65°C to +150°C

Ambient Temperature with

Power Applied -55°C to +125°C

Supply Voltage with

Respect to Ground -0.5 V to +7.0 V

DC Input Voltage -1.5 V to Vcc + 0.5 V

DC Output or I/O Pin Voltage -0.5 V to Vcc + 0.5 V

# OPERATING RANGES

#### Commercial (C) Devices

Ambient Temperature (T<sub>A</sub>)

Operating in Free Air 0°C to +75°C

Supply Voltage (Vcc)

with Respect to Ground

+4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

# DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Descrip	otion	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Volta	ge	IOH = −3.2 mA VIN = VIH or VIL VCC = Min.	2.4		٧
Vol	Output LOW Voltag	je	IOL = 24 mA VIN = VIH OF VIL VCC = MIN.		0.5	٧
ViH	Input HIGH Voltage		Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
ViL	Input LOW Voltage		Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		8.0	٧
Vı	Input Clamp Voltage		lin = −18 mA, Vcc = Min.		-1.2	٧
lıн	Input HIGH Curren	t	V <sub>IN</sub> = 2.7 V, V <sub>CC</sub> = Max. (Note 2)	l	25	μА
İıL	Input LOW Current		V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max. (Note 2)		-250	μА
İı	Maximum Input Cu	rrent	Vin = 5.5 V, Vcc = Max.		100	μА
Іохн	Off-State Output Le	eakage	Vout = 2.7 V, Vcc = Max. Vin = Vihor Vil (Note 2)		100	μА
lozi	Off-State Output Leakage Current LOW		Vout = 0.4 V, Vcc = Max. Vin = Vih or Vil (Note 2)		-100	μА
Isc	Output Short-Circuit Current		Vout = 0.5 V, Vcc = Max. (Note 3)	-30	-130	mA
lcc	Supply Current	16L8 16R8/6/4	V <sub>IN</sub> = 0 V, Outputs Open (lout = 0 mA) V <sub>CC</sub> = Max.		155 180	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vcc = 0.5 V
  has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Description	Test Conditions		Тур.	Unit
Cin	Input Capacitance	VIN = 2.0 V	Vcc = 5.0 V	7	
Соит	Output Capacitance	Vout = 2.0 V	T <sub>A</sub> = 25°C f = 1 MHz	7	pF

#### Note:

 These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

# **SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)**

Parameter Symbol	Parameter Des	Parameter Description					Unit
tpo		ut or Feedback to mbinatorial Output		16L8, 16R6, 16R4		25	ns
ts	Setup Time from	m Input or Feedback to	Clock		25		ns
tн	Hold Time						ns
tco	Clock to Outpur	t				15	ns
twL	Clock Width	LOW	LOW		15		ns
twn		HIGH		16R8, 16R6,	15		ns
	Maximum	External Feedback	1/(ts + tco)	16R4	25		MHz
fmax	Frequency	Internal Feedback (	Internal Feedback (fcnt)		28.5		MHz
	(Note 4)	No Feedback	1/(tw+ + twL)		33		MHz
tezx	OE to Output E	nable				20	ns
texz	OE to Output Disable					20	ns
tea .	Input to Output Enable Using Product Term Control			16L8, 16R6,		25	ns
ter	Input to Output Disable Using Product Term Control			16R4		25	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Calculated from measured fMAx internal.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.



Storage Temperature -65°C to +150°C

Ambient Temperature with

Power Applied -55°C to +125°C

Supply Voltage with

Respect to Ground -0.5 V to +7.0 V

DC Input Voltage -1.5 V to +5.5 V

DC Output or I/O Pin Voltage 5.5 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

#### **OPERATING RANGES**

#### Commercial (C) Devices

Ambient Temperature (T<sub>A</sub>)

Operating in Free Air

Supply Voltage (Vcc)

with Respect to Ground

+4.75 V to +5.25 V

0°C to +75°C

Operating ranges define those limits between which the functionality of the device is guaranteed.

# DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	toH = -1 mA VIN = VIH or VIL Vcc = Min.	2.4		٧
Vol	Output LOW Voltage	IOL = 8 mA VIN = VIH OF VIL VCC = MIN.		0.5	V
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)	-	0.8	٧
Vi	Input Clamp Voltage	I <sub>IN</sub> = -18 mA, V <sub>CC</sub> = Min.		-1.5	V
liн	Input HIGH Current	Vin = 2.4 V, Vcc = Max. (Note 2)		25	μА
Iιί	Input LOW Current	Vin = 0.4 V, Vcc = Max. (Note 2)		-250	μА
lı .	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max.		100	μА
Іогн	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max. Vin = Vih or Vil (Note 2)		100	μΑ
lozı	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vih or Vil (Note 2)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max. (Note 3)	-30	-250	mA
Icc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (lout = 0 mA) V <sub>CC</sub> = Max.		55	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second.
   Vout = 0.5 V as been chosen to avoid test problems caused by tester ground degradation.



# **SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 1)**

Parameter Symbol	Parameter Des	rameter Description				Max.	Unit
tpo	Input or Feedba Combinatorial (					35	ns
ts	Setup Time from	m Input or Feedback to	n Input or Feedback to Clock				ns
th .	Hold Time						ns
tco	Clock to Output	or Feedback	16R8, 16R6,		25	ns	
tw∟	Clock Width	LOW	LOW		25		ns
twн		HIGH			25		ns
	Maximum	External Feedback	1/(ts + tco)		16		MHz
fmax	Frequency (Note 2)	No Feedback	1/(tw+ + twL)		20		MHz
tezx	OE to Output E	nable				25	ns
texz	OE to Output D	isable			25	ns	
tea	Input to Output Enable Using Product Term Control			16L8, 16R6,		35	ns
ten	Input to Output	Disable Using Product	Term Control	16R4		35	ns

- 1. See Switching Test Circuit for test conditions.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.



Storage Temperature -65°C to +150°C

Ambient Temperature

with Power Applied -55°C to +125°C

Supply Voltage with

Respect to Ground -0.5 V to +7.0 V

DC Input Voltage -1.2 V to +5.5 V

DC Input Current -30 mA to +5 mA

DC Output or I/O Pin Voltage -0.5 V to Vcc + 0.5 V

Static Discharge Voltage

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

#### **OPERATING RANGES**

Military Devices (Note 1)

Ambient Temperature (T<sub>A</sub>)

Operating in Free Air -55°C Min.

Operating Case (Tc)

Temperature 125°C Max.

Supply Voltage (Vcc)

with Respect to Ground

+4.50 V to +5.50 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

#### Note:

 Military products are tested at Tc = +25°C, +125°C, and -55°C, per MIL-STD-883.

# DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

2001 V

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	IOH = -2 mA VIN = VIH or VIL VCC = Min.	2.4		<b>V</b>
Vol	Output LOW Voltage	IOL = 12 mA VIN = VIH OR VIL VCC = Min.		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	٧
Vt	Input Clamp Voltage	I <sub>IN</sub> = −18 mA, Vcc = Min.		-1.2	<b>&gt;</b>
ĪН	Input HIGH Current	V <sub>IN</sub> = 2.7 V, V <sub>CC</sub> = Max. (Note 4)		25	μА
lıL	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max. (Note 4)		-250	μА
łı	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max.		1	mA
Іохн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max. Vin = Vih or Vil (Note 4)		100	μА
lozu	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vih or Vil (Note 4)		-100	μA
Isc	Output Short-Circuit Current	V <sub>OUT</sub> = 0.5 V, V <sub>CC</sub> = Max. (Note 5)	-30	~130	mA
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (IouT = 0 mA) V <sub>CC</sub> = Max.		200	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with
  respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values
  without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and lozL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V
  has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Descrip	tion	Test Conditions		Тур.	Unit
Cin	Input Capacitance	Corner Pins Middle Pins	VIN = 2.0 V	Vcc = 5.0 V T <sub>A</sub> = 25°C	10 5	pF
Соит	Output Capacitance		Vout = 2.0 V	f = 1 MHz	9	

#### Note:

#### **SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 2)**

					-10	1	-12		
Parameter Symbol	Parameter D	escription			Min. (Note 3)	Max.	Min. (Note 3)	Max.	Unit
tpo	Input or Feed Combinatoria				3	10	3	12	ns
ts	Setup Time fr	om Input or Feedbac	k to Clock		10		10		ns
tн	Hold Time				0_		0		ns
tco	Clock to Outp	ut			2	9	3	11	ns
tskew	Skew Betwee	n Registered Output	n Registered Outputs (Note 4)			1		1	ns
twL		1 5011		16R8,	8		8		ns
twn	Clock Width	HIGH		16R6, 16R4	8		8		ns
	Maximum	External Feedback	1/(ts + tco)	1	52.6		47.6		MHz
<b>f</b> MAX	Frequency	Internal Feedback (	fcnt)	1	60.6		60.6		MHz
_	(Note 5)	No Feedback	1/(tw+ + twL)	]	62.5		62.5		MHz
tezx	OE to Output	Enable (Note 5)			1	10	1	12	ns
texz	OE to Output	Disable (Note 5)		]	1	10	1	12	ns
tea		out to Output Enable Using Product		16L8, 16R6,	1	10	1	12	ns
ter	Input to Outp Term Control	ut Disable Using Pro (Note 5)	duct	16R4	1	10	1	12	ns

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- Minimum value for tpp, tco, tpzx, tpxz, tea, and ten parameters should be used for simulation purposes only and are not tested.
- 4. Skew is measured with all outputs switching in the same direction.
- 5. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



-65°C to +150°C Storage Temperature

Stresses above those listed under Absolute Maximum Rat-

ings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliabil-

ity. Programming conditions may differ. Absolute Maximum

Ratings are for system design reference; parameters given

Ambient Temperature

with Power Applied

-55°C to +125°C

Supply Voltage with

Respect to Ground

are not tested.

-0.5 V to +7.0 V

DC Input Voltage

-1.5 V to +5.5 V

DC Output or I/O Pin Voltage

5.5 V

Supply Voltage (Vcc)

Temperature

with Respect to Ground

**OPERATING RANGES** 

Operating in Free Air

Operating Case (Tc)

Military (M) Devices (Note 1)

Ambient Temperature (TA)

+4.50 V to +5.50 V

-55°C Min.

125°C Max.

Operating ranges define those limits between which the functionality of the device is guaranteed.

#### Note:

1. Military products are tested at Tc = +25°C, +125°C, and -55°C, per MIL-STD-883.

#### DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	I <sub>OH</sub> = -2 mA V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>CC</sub> = Min.	2.4		V
Vol	Output LOW Voltage	IOL = 12 mA VIN = VIH OR VIL VCC = Min.		0.5	V
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		>
ViL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	٧
Vı	Input Clamp Voltage	f <sub>IN</sub> = −18 mA, Vcc = Min.		-1.5	<b> </b>
lін	Input HIGH Current	V <sub>IN</sub> = 2.4 V, V <sub>CC</sub> = Max. (Note 4)		25	μА
l IL	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max. (Note 4)		-250	μΑ
lı .	Maximum Input Current	Vin = 5.5 V, Vcc = Max.		1	mA
Іохн	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max. Vin = Vih or Vit (Note 4)		100	μА
lozu	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vih or Vil (Note 4)		-100	μΑ
Isc	Output Short-Circuit Current	V <sub>O</sub> UT = 0.5 V, V <sub>C</sub> C = Max. (Note 5)	-30	-130	mA
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (lout = 0 mA) V <sub>CC</sub> = Max.		180	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- 5. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second, Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Description	Test Conditions	·	Тур.	Unit
Cin	Input Capacitance	V <sub>N</sub> = 2.0 V	Vcc = 5.0 V	9	
Соит	Output Capacitance	Vout = 2.0 V	T <sub>A</sub> = 25°C f = 1 MHz	10	pF

#### Note:

## **SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 2)**

Parameter Symbol	Parameter Des	Parameter Description					Unit
tpo	Input or Feedback to Combinatorial Output		16L8, 16R6, 16R4		20	ns	
ts	Setup Time from Input or Feedback to Clock				20		ns
tн	Hold Time				0		ns
tco	Clock to Output	or Feedback			15	ns	
tw.		LOW		16R8, 16R6,	12		ns
twn	Clock Width HIGH			16R4	12		ns
fmax	Maximum Frequency (Note 3)	External Feedback	1/(ts + tco)		28.5		MHz
		No Feedback	1/(tw+ + twL)		41.6		MHz
tezx	OE to Output E	nable (Note 4)				20	ns
texz	OE to Output D	isable (Note 4)				20	ns
<b>tea</b>	Input to Output Enable Using Product Term Control (Note 4)			16L8, 16R6,		25	ns
ten	Input to Output Term Control (I	Disable Using Product Note 4)	-	16R4		20	ns

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MiL-STD-883, Method 5005, unless otherwise noted.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature -65°C to +150°C

Ambient Temperature

with Power Applied

-55°C to +125°C

Supply Voltage with

Respect to Ground

-0.5 V to +7.0 V

5.5 V

DC Input Voltage -1.5 V to +5.5 V

DC Output or I/O Pin Voltage

**OPERATING RANGES** 

Military (M) Devices (Note 1)

Ambient Temperature (T<sub>A</sub>)

Operating in Free Air

Operating Case (Tc)

Temperature

125°C Max.

-55°C Min.

Supply Voltage (Vcc)

with Respect to Ground

+4.50 V to +5.50 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

Operating ranges define those limits between which the functionality of the device is guaranteed.

#### Note:

1. Military products are tested at Tc = +25°C, +125°C, and -55°C, per MIL-STD-883.

#### DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	I <sub>OH</sub> = −2 mA V <sub>IN</sub> ≈ V <sub>IH</sub> or V <sub>IL</sub> V <sub>CC</sub> = Min.	2.4		٧
Vol	Output LOW Voltage	IoL = 12 mA VIN = VIH or VIL Vcc = Min.		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0	-	٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	٧
Vi	Input Clamp Voltage	I <sub>IN</sub> = -18 mA, V <sub>CC</sub> = Min.		-1.5	
I <sub>IH</sub>	Input HIGH Current	V <sub>IN</sub> = 2.4 V, V <sub>CC</sub> = Max. (Note 4)		25	μΑ
lıı.	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max. (Note 4)		-250	μА
l <sub>1</sub>	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max.		_1	mA
Іохн	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max. Vin = Vih or Vil (Note 4)		100	μА
lozi	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vih or Vil (Note 4)		-100	μA
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max. (Note 5)	-30	-130	mA
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (Iout = 0 mA) V <sub>CC</sub> = Max.		90	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- 5. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vour = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Description	Test Conditions		Тур.	Unit
Cin	Input Capacitance	VIN = 2.0 V	Vcc ≈ 5.0 V	7	
Соит	Output Capacitance	Vout = 2.0 V	T <sub>A</sub> = 25°C f = 1 MHz	7	pF

#### Note:

#### **SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 2)**

Parameter Symbol	Parameter Description					Max.	Unit
tpo	Input or Feedba Combinatorial (					30	ns
ts	Setup Time from	m Input or Feedback to	Clock		30		ns
tн	Hold Time				0		ns
tco	Clock to Output	t or Feedback				20	ns
twL	Clock Width	LOW		16R8, 16R6,	20		ns
twн		HIGH		16R4	20		ns
	Maximum	External Feedback	1/(ts + tco)		20		MHz
fmax	Frequency (Note 3)	No Feedback	1/(twh + twl)		25		MHz
tezx	OE to Output E	nable (Note 4)				25	ns
texz	OE to Output D	isable (Note 4)	·			25	ns
<b>t</b> EA	Input to Output Term Control (I	ut Enable Using Product I (Note 4)		16L8, 16R6,		30	ns
ter	Input to Output Term Control (I	Disable Using Product Note 4)		16R4		30	ns

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified '
where capacitance may be affected.



-65°C to +150°C Storage Temperature

Ambient Temperature

with Power Applied

-55°C to +125°C

Supply Voltage with

Respect to Ground

-0.5 V to +7.0 V -1.5 V to +5.5 V

DC Input Voltage

DC Output or I/O Pin Voltage

OPERATING RANGES

Military (M ) Devices (Note 1)

Ambient Temperature (T<sub>A</sub>)

Operating in Free Air

Operating Case (Tc)

Temperature

125°C Max

-55°C Min.

Supply Voltage (Vcc)

with Respect to Ground

+4.50 V to +5.50 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested

Operating ranges define those limits between which the functionality of the device is guaranteed.

#### Note:

1. Military products are tested at Tc = +25°C, +125°C, and -55°C, per MIL-STD-883.

#### DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

5.5 V

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	IOH = -2 mA VIN = VIH or VIL VCC = Min.	2.4		٧
Vol	Output LOW Voltage	IOL = 12 mA VIN = VIH OR VIL VCC = MIN.		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0	_	V
ViL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	٧
Vı	Input Clamp Voltage	In = -18 mA, Vcc = Min.		-1.5	٧
lin	Input HIGH Current	V <sub>IN</sub> = 2.4 V, V <sub>CC</sub> = Max. (Note 4)		25	μА
ln.	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max. (Note 4)	,	-250	μА
lı	Maximum Input Current	Vin = 5.5 V, Vcc = Max.		1	mA
ЮZН	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max. Vin = Vih or Vil (Note 4)		100	μА
lozu	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vih or Vil (Note 4)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max. (Note 5)	-30	-130	mA
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (lout = 0 mA) V <sub>CC</sub> = Max.		180	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
- 4. I/O pin leakage is the worst case of I/L and IOZL (or I/H and IOZH).
- 5. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

Parameter Symbol	Parameter Description	Test Conditions		Тур.	Unit
Cin	Input Capacitance	VIN = 2.0 V	Vcc ≈ 5.0 V	7	
Соит	Output Capacitance	Vout = 2.0 V	Ta = 25°C f = 1 MHz	7	pF

#### Note:

## **SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 2)**

Parameter Symbol	Parameter Description					Max.	Unit
tPD	Input or Feedba Combinatorial (			16L8, 16R6, 16R4		30	ns
ts	Setup Time from	m Input or Feedback to	Clock		30		ns
tн	Hold Time				0		ns
tco	Clock to Output	or Feedback				20	ns
twl	Clock Width	LOW	LOW		20		ns
twн		HIGH	HIGH		20		ns
	Maximum	External Feedback	1/(ts + tco)		20		MHz
1MAX	Frequency (Note 3)	No Feedback	1/(tw+ + twL)		25		MHz
tezx	OE to Output E	nable (Note 4)				25	ns
texz	OE to Output D	E to Output Disable (Note 4)				25	ns
tea .	Input to Output Enable Using Product Term Control (Note 4)		16L8, 16R6,		30	ns	
ter	Input to Output Term Control (I	Disable Using Product Note 4)		16R4		30	ns

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- 4. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature

-65°C to +150°C

Ambient Temperature

with Power Applied

~55°C to +125°C

Supply Voltage with

Respect to Ground

-0.5 V to +7.0 V

DC Input Voltage

-1.5 V to +5.5 V

DC Output or I/O Pin Voltage

5.5 V

#### **OPERATING RANGES**

#### Military (M ) Devices (Note 1)

Ambient Temperature (Ta)

Operating in Free Air

-55°C Min.

Operating Case (Tc)

Temperature

125°C Max.

Supply Voltage (Vcc)

with Respect to Ground

+4.50 V to +5.50 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

Operating ranges define those limits between which the functionality of the device is quaranteed.

#### Note:

 Military products are tested at Tc = +25°C, +125°C, and -55°C, per MIL-STD-883.

# DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	I <sub>OH</sub> = -1 mA V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>CC</sub> = Min.	2.4		٧
Vol	Output LOW Voltage	tot = 4 mA VIN = VIH or VIL VCC = Min.		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		8.0	٧
Vı	Input Clamp Voltage	In = -18 mA, Vcc = Min.		-1.5	V
Ін	Input HIGH Current	V <sub>IN</sub> = 2.4 V, V <sub>CC</sub> = Max. (Note 4)		25	μΑ
lii.	Input LOW Current	V <sub>IN</sub> = 0.4 V, V <sub>CC</sub> = Max. (Note 4)		-250	μА
l <sub>i</sub>	Maximum Input Current	V <sub>IN</sub> = 5.5 V, V <sub>CC</sub> = Max.		1	mA
Іогн	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max. Vin = Vih or Vil (Note 4)		100	μA
lozL	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vih or Vil (Note 4)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max. (Note 5)	-30	-250	mA
lcc	Supply Current	V <sub>IN</sub> = 0 V, Outputs Open (lout = 0 mA) Vcc = Max.		55	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- 5. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

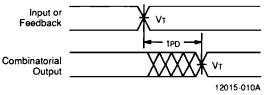


## **SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 1)**

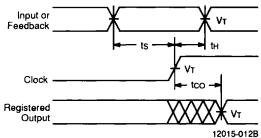
Parameter Symbol	Parameter Des	Min.	Max.	Unit			
teo	Input or Feedba Combinatorial			16L8, 16R6, 16R4		50	ns
ts	Setup Time fro	m Input or Feedback to	Clock		50		ns
tн	Hold Time				0		ns
tco	Clock to Output	t or Feedback	or Feedback			25	ns
twL	Clock Width	LOW	LOW 1		25		ns
twn		HIGH			25		ns
4	Maximum	External Feedback	1/(ts + tco)		13.3		MHz
fmax	Frequency (Note 2)	No Feedback	1/(tw+ + twL)		20		MHz
tpzx	OE to Output E	nable (Note 3)				25	ns
texz	OE to Output D	E to Output Disable (Note 3)				25	ns
tea	Input to Output Enable Using Product Term Control (Note 3)		16L8, 16R6,		45	ns	
ter	Input to Output Term Control (f	Output Disable Using Product		16R4		45	ns

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 2. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

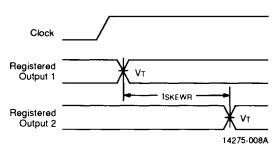
#### **SWITCHING WAVEFORMS**



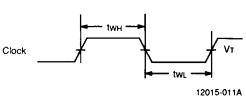
**Combinatorial Output** 



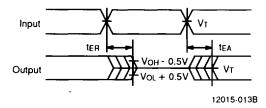
Registered Output



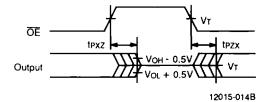
**Registered Output Skew** 



**Clock Width** 



Input to Output Disable/Enable



**OE** to Output Disable/Enable

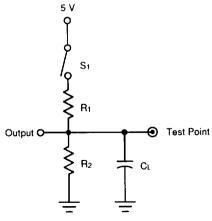
- 1.  $V_T = 1.5 V$
- 2. Input pulse amplitude 0 V to 3.0 V
- 3. Input rise and fall times 2-3 ns typical.

# **KEY TO SWITCHING WAVEFORMS**

WAVEFORM	INPUTS	OUTPUTS
	Must be Steady	Will be Steady
	May Change from H to L	Will be Changing from H to L
	May Change from L to H	Will be Changing from L to H
	Don't Care; Any Change Permitted	Changing, State Unknown
$\longrightarrow \longleftarrow$	Does Not Apply	Center Line is High- Impedance "Off" State

KS000010-PAL

# **SWITCHING TEST CIRCUIT**

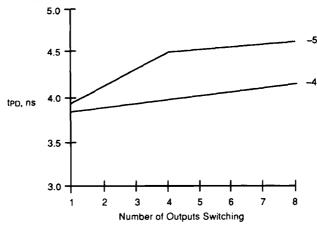


12350-019A

			Comm	nercial	Measured
Specification	S <sub>1</sub>	CL	Rı	R <sub>2</sub>	Output Value
tpp, tco	Closed				1.5 V
tPZX, tEA	Z → H: Open Z → L: Closed	50 pF	200 Ω	200 Ω	1.5 V
texz, ten	H → Z: Open L → Z: Closed	5 pF			H → Z: V <sub>OH</sub> − 0.5 V L → Z: V <sub>OL</sub> + 0.5 V

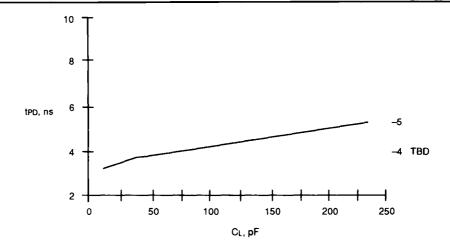
# **MEASURED SWITCHING CHARACTERISTICS for the PAL16R8-4/5**

V<sub>CC</sub> = 4.75 V, T<sub>A</sub> = 75°C (Note 1)



tPD vs. Number of Outputs Switching

14275-010A



tpb vs. Load Capacitance Vcc = 5.25 V, TA = 25°C

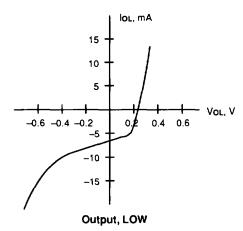
14275-011A

#### Note

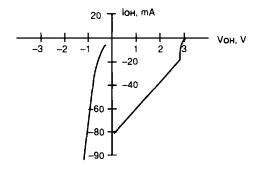
 These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where tpp may be affected.

# **CURRENT VS. VOLTAGE (I-V) CHARACTERISTICS for the PAL16R8-4/5**

Vcc = 5.0 V,  $T_A = 25$ °C

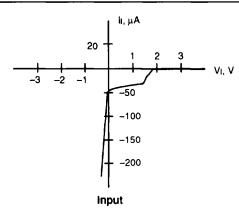


10240-003B



**Output, HIGH** 

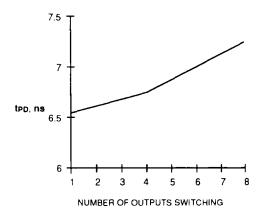
10240-004B



10240-005A

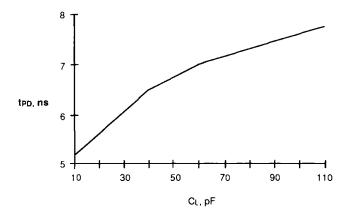
## **MEASURED SWITCHING CHARACTERISTICS for the PAL16R8-7**

 $V_{CC} = 4.75 \text{ V}, T_A = 75^{\circ}\text{C} \text{ (Note 1)}$ 



tpp vs. Number of Outputs Switching

10240-001A



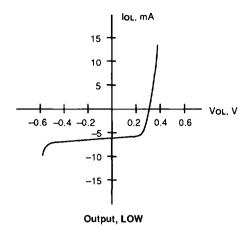
tpp vs. Load Capacitance

10240-002A

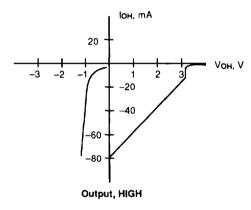
#### Note:

1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where typ may be affected.

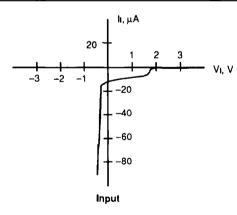
# CURRENT VS. VOLTAGE (I-V) CHARACTERISTICS for the PAL16R8-7 $V_{\text{CC}} = 5.0 \ \text{V}, \ T_{\text{A}} = 25 ^{\circ}\text{C}$



10240-003A

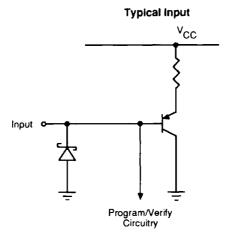


10240-004A



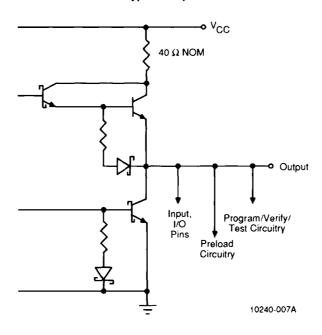
10240-005A

#### INPUT/OUTPUT EQUIVALENT SCHEMATICS



10240-006A

## **Typical Output**



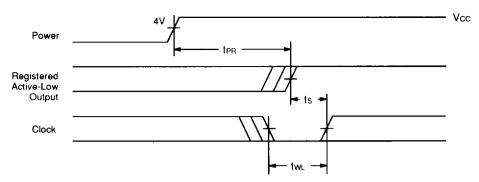
#### **POWER-UP RESET**

The power-up reset feature ensures that all flip-flops will be reset to LOW after the device has been powered up. The output state will be HIGH due to the inverting output buffer. This feature is valuable in simplifying state machine initialization. A timing diagram and parameter table are shown below. Due to the synchronous operation of the power-up reset and the wide range of ways Vcc

can rise to its steady state, two conditions are required to ensure a valid power-up reset. These conditions are:

- 1. The Vcc rise must be monotonic.
- Following reset, the clock input must not be driven from LOW to HIGH until all applicable input and feedback setup times are met.

Parameter Symbol	Parameter Description	Max.	Unit
tpR	Power-up Reset Time	1000	ns
ts	Input or Feedback Setup Time	See Switch	ing
tw∟	Clock Width LOW	Characteris	tics



12350-024A

Power-Up Reset Waveform